TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

# 2SB907

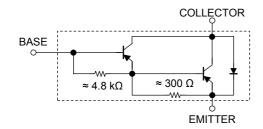
Switching Applications Hammer Drive, Pulse Motor Drive Applications Power Amplifier Applications

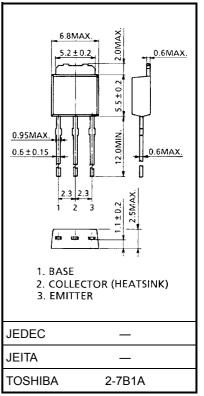
- High DC current gain:  $h_{FE}$  (1) = 2000 (min) ( $V_{CE}$  = -2 V,  $I_C$  = -1 A)
- Low saturation voltage:  $V_{CE}$  (sat) = -1.5 V (max) (I<sub>C</sub> = -2 A)
- Complementary to 2SD1222.

#### Maximum Ratings (Ta = 25°C)

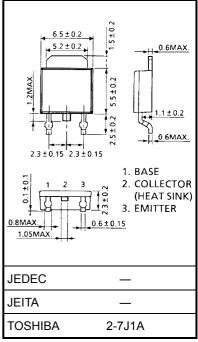
Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	-60	V	
Collector-emitter voltage		V <sub>CEO</sub>	-40	V	
Emitter-base voltage		V <sub>EBO</sub>	-5	V	
Collector current		Ι <sub>C</sub>	-3	А	
Base current		I <sub>B</sub>	-0.3	А	
Collector power dissipation	Ta = 25°C	Pc	1.0	w	
	Tc = 25°C	ГC	15		
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

## **Equivalent Circuit**





Weight: 0.36 g (typ.)

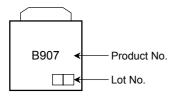


Weight: 0.36 g (typ.)

**Electrical Characteristics (Ta = 25°C)** 

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	$V_{CB} = -60 \text{ V}, \text{ I}_{E} = 0$	_	—	-20	μA
Emitter cut-off current		I <sub>EBO</sub>	$V_{EB} = -5 V, I_C = 0$	_	_	-2.5	mA
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = −25 mA, I <sub>B</sub> = 0	-40	_	_	V
DC current gain		h <sub>FE (1)</sub>	$V_{CE} = -2 V, I_C = -1 A$	2000	_	_	
		h <sub>FE (2)</sub>	$V_{CE} = -2 V, I_C = -3 A$	1000	_	_	
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = -2 A, I <sub>B</sub> = -4 mA	_	—	-1.5	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = -2 A, I <sub>B</sub> = -4 mA	_	—	-2.0	V
Switching time	Turn-on time	t <sub>on</sub>	OUTPUT IB2 IN PUT IN PUT IN PUT IN $V_{CC} = -30 V$ $V_{CC} = 1\%$	_	0.30	_	
	Storage time	t <sub>stg</sub>		_	0.60	_	μs
	Fall time	t <sub>f</sub>			0.25	_	

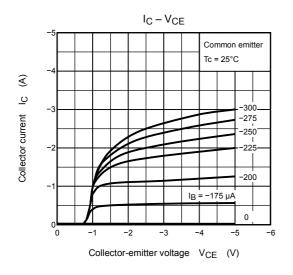
## Marking

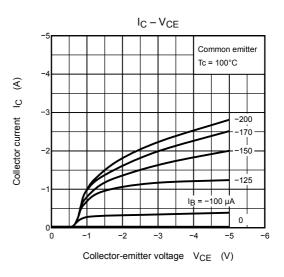


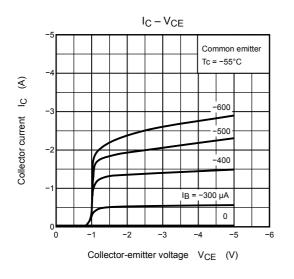
## Explanation of Lot No.

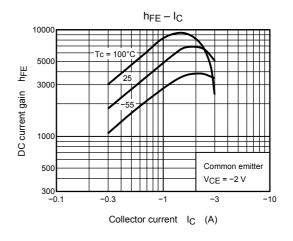
Month of manufacture: January to December are denoted by letters A to L respectively.

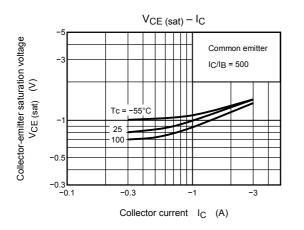
## **TOSHIBA**

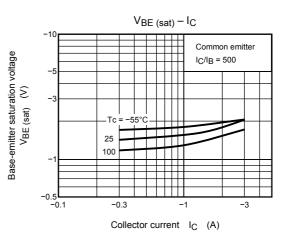




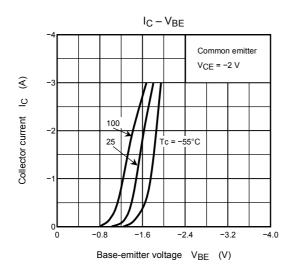


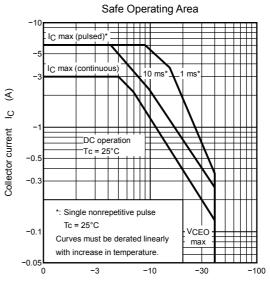




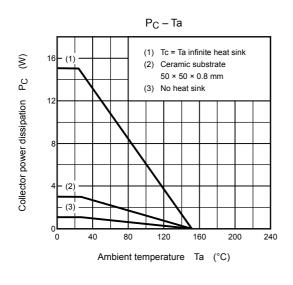


# TOSHIBA





Collector-emitter voltage  $V_{CE}$  (V)



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